

Product Summary

V _{(BR)DSS}	R _{DS(on)TYP}	I _D	
100V	110mΩ@10V	5A	
	160mΩ@4.5V) JA	



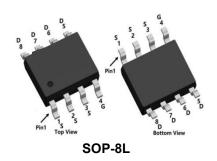
Feature

- High power and current handing capability
- Surface mount package

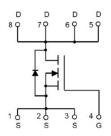
Application

- Battery Switch
- DC/DC Converter

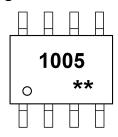
Package



Circuit diagram



Marking



1005

:Device Code :Week Code

Order Information

Device	Package	Unit/Tape
SP010N110GP8	SOP-8L	4000



Absolute maximum ratings (Ta=25℃, unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V _{DSS}	100	V
Gate-Source Voltage	V _{GSS}	±20	V
Continuous Drain Current	ID	5	A
Pulse Drain Current Tested	I _{DM}	20	A
Power Dissipation	P _D	1.9	W
Thermal Resistance Junction-to-Ambient	Reja	65.8	°C/W
Storage Temperature Range	T _{STG}	-55 to 150	°C
Operating Junction Temperature Range	TJ	-55 to 150	°C

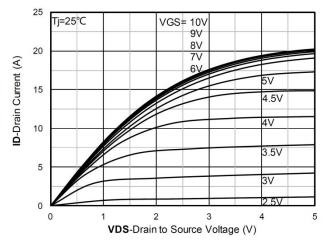
Electrical characteristics (Ta=25°C, unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Static Characteristics			•			
Drain-Source Breakdown Voltage	BV _{DSS}	VGS=0V , ID=250μA	100	-	-	V
Drain-Source Leakage Current	I _{DSS}	VDS=80V , VGS=0V	-	-	1	uA
Gate-Source Leakage Current	I _{GSS}	VGS=±20V, VDS=0V	-	-	±100	nA
Gate Threshold Voltage	V _{GS(th)}	VDS=VGS , ID=250μA	1	1.8	2.5	V
Static Drain-Source On-Resistance	Б	VGS=10V , ID =3A	-	110	140	mΩ
	R _{DS(ON)}	VGS=4.5V , ID =2A	-	160	300	
Dynamic characteristics	•		•	•	•	
Input Capacitance	C _{iss}	VDS=50V , VGS=0V , f=1MHz	-	206	-	pF
Output Capacitance	Coss		-	29	-	
Reverse Transfer Capacitance	Crss		-	1.4	-	
Total Gate Charge	Qg		-	4.3	-	nC
Gate-Source Charge	Qgs	VDS=50V , VGS=10V , ID=3A	-	1.5	-	
Gate-Drain Charge	Q _{gd}			1.1	-	1
Switching Characteristics	•					
Turn-On Delay Time	t _{d(on)}	- - - - - VDD=50V VGS=10V , RG=2Ω, ID=3A	-	14.7	-	
Turn-On Rise Time	t _r		-	3.5	-	nS
Turn-Off Delay Time	t _{d(off)}		-	20.9	-	
Turn-Off Fall Time	t _f	1		2.7	-	1
Source-Drain Diode characteristics						
Diode Forward Voltage	V _{SD}	VGS=0V , IS=1A , TJ=25℃	-	-	1.2	V

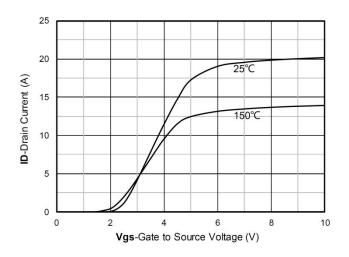
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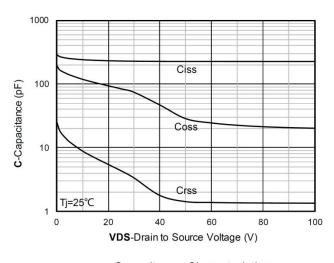
Typical Characteristics



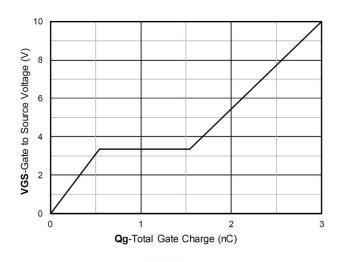
Output Characteristics



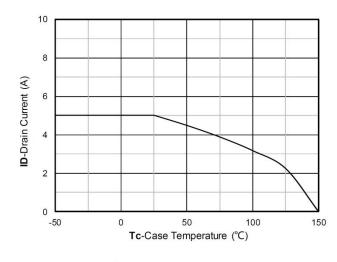
Transfer Characteristics



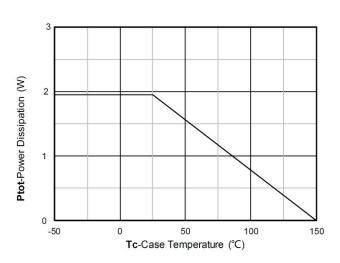
Capacitance Characteristics



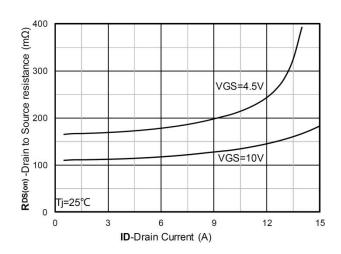
Gate Charge



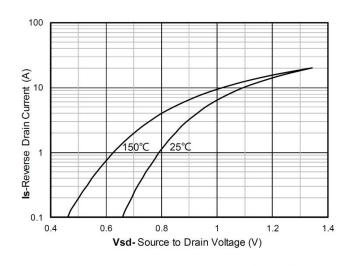
Current dissipation



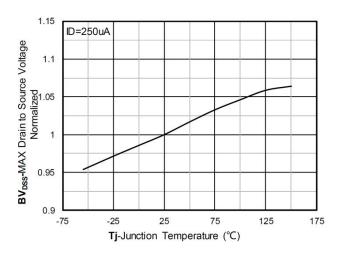
Power dissipation



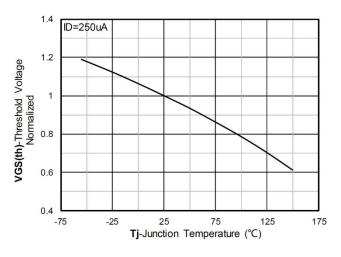
RDS(on) VS Drain Current



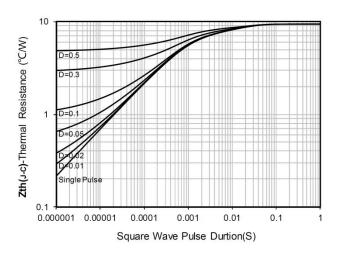
Forward characteristics of reverse diode



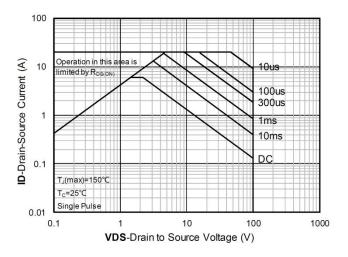
Normalized breakdown voltage



Normalized Threshold voltage



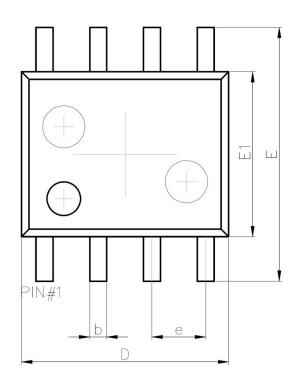
Maximum Transient Thermal Impedance

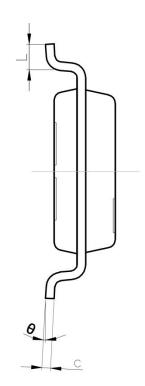


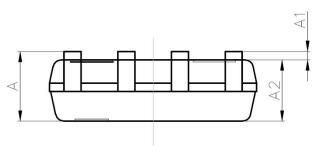
Safe Operation Area



SOP-8L Package Information







Complete	Dimensions In Millimeters		
Symbol	Min.	Max.	
A	1.35	1.75	
A1	0.10	0.25	
A2	1.35	1.55	
b	0.33	0.51	
С	0.17	0.25	
D	4.80	5.00	
е	1.27 REF.		
Е	5.80	6.20	
E1	3.80	4.00	
L	0.40	1.27	
θ	0°	8°	